

FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. MICRON.098CDV2	APPLICATION NO. <u>Unknown</u>
INFORMATION DISCLOSURE STATEMENT BY APPLICANT		APPLICANT Basceri et al.	
(USE SEVERAL SHEETS IF NECESSARY)		FILING DATE Herewith	GROUP <u>354183</u> <u>2823</u>

U.S. PATENT DOCUMENTS						
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE (IF APPROPRIATE)
WB	1 5,335,138	8/2/94	Sandhu et al.	361	383	
WB	2 5,406,445	4/11/95	Fujii et al.	361	385	
WB	3 5,506,166	4/9/96	Sandhu et al.	438	396	
WB	4 5,717,234	2/10/98	Si et al.	257	295	
WB	5 5,781,404	7/14/98	Summerfelt et al.	361	321.5	
WB	6 5,783,253	7/21/98	Roh	427	81	
WB	7 5,889,299	3/30/99	Abe et al.	257	295	
WB	8 5,973,911	10/26/99	Nishioka	361	313	
WB	9 6,010,931	1/4/00	Sun et al.	438	48	
WB	10 6,117,482	9/12/00	Kawahara et al.	727	18	
WB	11 6,136,639	10/24/00	Seon	438	238	
WB	12 6,319,764 B1	11/20/01	Basceri et al.	438	240	

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)	
WB	13	Hiromi Itoh et al., "Integration of BST Thin Film for Dram Fabrication", Integrated Ferroelectrics, 1995 Vol. 11, pp. 101-109
WB	14	C. Basceri, "An Important Failure Mechanism in MOCVD (Ba,Sr)TiO <sub>3</sub> Thin Films: Resistance Degradation", Ferroelectric Thin Films IV, Materials Research Society, Symposium Proceedings Volume 493, 1998, pp. 9-14
WB	15	Chung Ming Chu and Pang Lin, "Electric Properties and Crystal Structure of a (Ba,Sr)TiO <sub>3</sub> Films Prepared at Low Temperatures on a LaNiO <sub>3</sub> Electrode by Radio-Frequency Magnetron Sputtering", Appl. Phys. Lett., Vol. 70 (2), 13 January 1997, pp.249-51
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EXAMINER	<u>William P. Basceri</u>	DATE CONSIDERED	<u>18 APR 03</u>
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED; INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.			

<p>U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE</p> <p>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p>(USE SEVERAL SHEETS IF NECESSARY)</p>		<p>ATTY. DOCKET NO. MICRON.098CDV2</p>	<p>APPLICATION NO. 10/615,524</p>
		<p>APPLICANT Basceri et al.</p>	
		<p>FILING DATE July 3, 2003</p>	<p>GROUP 2823</p>

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EXAMINER <i>William M. Brewster</i>	DATE CONSIDERED <i>14 APR 05</i>
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\*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> <i>(Multiple sheets used when necessary)</i>		Application No.	10/615,524
		Filing Date	July 3, 2003
		First Named Inventor	Basceri et al.
		Art Unit	2823
SHEET 1 OF 1	FEB 25 2005	Examiner	William M. Brewster
		Attorney Docket No.	MICRON.098CDV2

PATENT & TRADEMARK INFORMATION					
PATENT DOCUMENTS					
Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
W/B	1.	6,852,593	02/08/05	Basceri et al. 438/253	x
W/B	2.	6,855,971	02/15/05	Basceri et al. 257/295	x

FOREIGN PATENT DOCUMENTS						
Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear	T <sup>1</sup>
W/B	3.	EPO 0 617 439 A2	03-24-1994	Matsushita Electric Industrial Co.	x	x
W/B	4.	JP 406 333 772A	12-02-1994	Fujii et al.	x	x

NON PATENT LITERATURE DOCUMENTS						
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				T <sup>1</sup>
W/B	5.	Copy of Claims as allowed in Amendment filed August 14, 2004 in Application No. 10/614,418, filed July 3, 2003				x
W/B	6.	Copy of March 14, 2003 Office Action in U.S. Patent No. 6,855,971 causing JP 406 333 772A to be listed.				x

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Examiner Signature <i>William M. Brewster</i>	Date Considered <i>14 APR 05</i>
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

T<sup>1</sup> - Place a check mark in this area when an English language Translation is attached.